

BAV19WS-V, BAV20WS-V, BAV21WS-V

Vishay Semiconductors

Small Signal Switching Diodes, High Voltage

FEATURES

Silicon epitaxial planar diodes

designation BAV19W-V to BAV21W-V

• For general purpose



- These diodes are also available in other case styles including: the DO-35 case with the type designation BAV19 to BAV21, the MiniMELF case with the type designation BAV100 to BAV103, the SOT-23 case with the type designation BAS19 to BAS21 and the SOD-123 case with the type
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

| PARTS TABLE | | | | | | | |
|-------------|-------------------------|----------------------------------|--------------|--------------------------|---------------|--|--|
| PART | TYPE DIFFERENTIATION | ORDERING CODE | TYPE MARKING | INTERNAL CONSTRUCTION | REMARKS | | |
| BAV19WS-V | V _R = 100 V | BAV19WS-V-GS18 or BAV19WS-V-GS08 | A8 | Single diode | Tape and reel | | |
| BAV20WS-V | V _R = 150 V | BAV20WS-V-GS18 or BAV20WS-V-GS08 | A9 | Single diode | Tape and reel | | |
| BAV21WS-V | V _R = 200 V | BAV21WS-V-GS18 or BAV21WS-V-GS08 | AA | Single diode | Tape and reel | | |

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) PARAMETER TEST CONDITION PART SYMBOL VALUE UNIT | | | | | | | |
|---|---------------------------------|-----------|--------------------|-------|------|--|--|
| PARAMETER | TEST CONDITION | PARI | STMBOL | VALUE | UNIT | | |
| | | BAV19WS-V | V _R | 100 | V | | |
| Continuous reverse voltage | | BAV20WS-V | V _R | 150 | V | | |
| | | BAV21WS-V | V _R | 200 | V | | |
| | | BAV19WS-V | V _{RRM} | 120 | V | | |
| Repetitive peak reverse voltage | | BAV20WS-V | V _{RRM} | 200 | V | | |
| | | BAV21WS-V | V _{RRM} | 250 | V | | |
| Forward continuous current (1) | | | I _F | 250 | mA | | |
| Rectified current (average) half wave recitification with resistive load ⁽¹⁾ | | | I _{F(AV)} | 200 | mA | | |
| Repetitive peak forward current ⁽¹⁾ | f ≥ 50 Hz, θ = 180 °C | | I _{FRM} | 625 | mA | | |
| Surge forward current | t < 1 s, T _J = 25 °C | | I _{FSM} | 1 | А | | |
| Power dissipation ⁽¹⁾ | | | P _{tot} | 200 | mW | | |

Note

⁽¹⁾ Valid provided that leads are kept at ambient temperature

| THERMAL CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified) | | | | | | |
|--|----------------|-------------------|---------------|------|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | | |
| Thermal resistance junction to ambient air ⁽¹⁾ | | R _{thJA} | 650 | K/W | | |
| Junction temperature ⁽¹⁾ | | Tj | 150 | °C | | |
| Storage temperature range ⁽¹⁾ | | T _{stg} | - 65 to + 175 | °C | | |

Note

⁽¹⁾ Valid provided that leads are kept at ambient temperature

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1

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MECHANICAL DATA

Case: SOD-323

Weight: approx. 4.3 mg

Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/3K per 7" reel (8 mm tape), 15K/box



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| ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|--|---|-----------|-----------------|------|------|------|------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | I _F = 100 mA | | V _F | | | 1 | V |
| Forward voltage | I _F = 200 mA | | V _F | | | 1.25 | V |
| | V _R = 100 V | BAV19WS-V | I _R | | | 100 | nA |
| | $V_{R} = 100 \text{ V}, \text{ T}_{J} = 100 ^{\circ}\text{C}$ | BAV20WS-V | I _R | | | 15 | μA |
| Repetitive peak reverse voltage | V _R = 150 V | BAV21WS-V | I _R | | | 100 | nA |
| Repetitive peak reverse voltage | V _R = 150 V, T _J = 100 °C | BAV19WS-V | I _R | | | 15 | μA |
| | V _R = 200 V | BAV20WS-V | I _R | | | 100 | nA |
| | $V_{R} = 200 \text{ V}, \text{ T}_{J} = 100 ^{\circ}\text{C}$ | BAV21WS-V | I _R | | | 15 | μA |
| Dynamic forward resistance | I _F = 10 mA | | r _f | | 5 | | Ω |
| Diode capacitance | V _R = 0, f = 1 MHz | | CD | | 1.5 | | pF |
| Reverse recovery time | $I_F = 30 \text{ mA}, I_R = 30 \text{ mA}, \\ i_R = 3 \text{ mA}, R_L = 100 \Omega$ | | t _{rr} | | | 50 | ns |

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

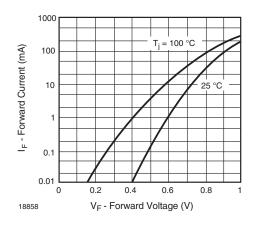


Fig. 1 - Forward Current vs. Forward Voltage

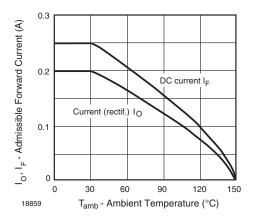


Fig. 2 - Admissible Forward Current vs. Ambient Temperature

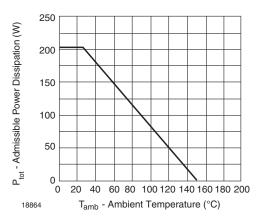


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

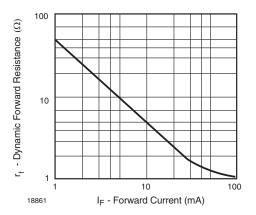


Fig. 4 - Dynamic Forward Resistance vs. Forward Current

Rev. 1.5, 02-Aug-12

2

Document Number: 85726

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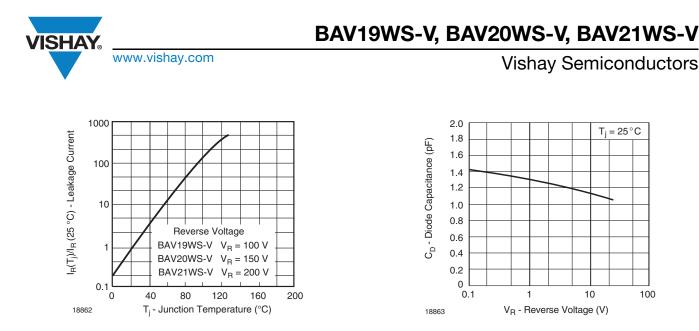
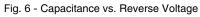
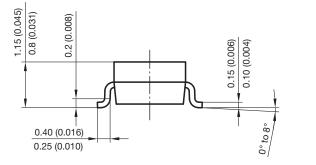
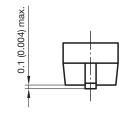


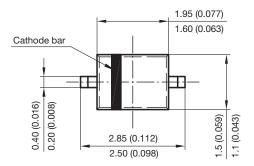
Fig. 5 - Leakage Current vs. Junction Temperature



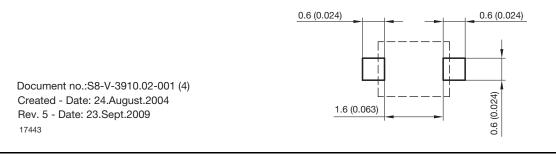
PACKAGE DIMENSIONS in millimeters (inches): SOD-323











Rev. 1.5, 02-Aug-12

3

Document Number: 85726

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